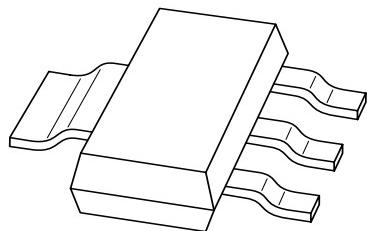


DATA SHEET



BAT160 series Schottky barrier double diodes

Product specification
Supersedes data of 1999 Mar 26

1999 Sep 20

Schottky barrier double diodes**BAT160 series****FEATURES**

- Low switching losses
- Capability of absorbing very high surge current
- Fast recovery time
- Guard ring protected
- Plastic SMD package.

APPLICATIONS

- Low power switched-mode power supplies
- Rectification
- Polarity protection.

DESCRIPTION

Planar Schottky barrier double diodes encapsulated in a SOT223 plastic SMD package.

MARKING

TYPE NUMBER	MARKING CODE
BAT160A	AT160A
BAT160C	AT160C
BAT160S	AT160S

PINNING

PIN	BAT160		
	A	C	S
1	k_1	a_1	a_1
2	n.c.	n.c.	n.c.
3	k_2	a_2	k_2
4	a_1, a_2	k_1, k_2	k_1, a_2

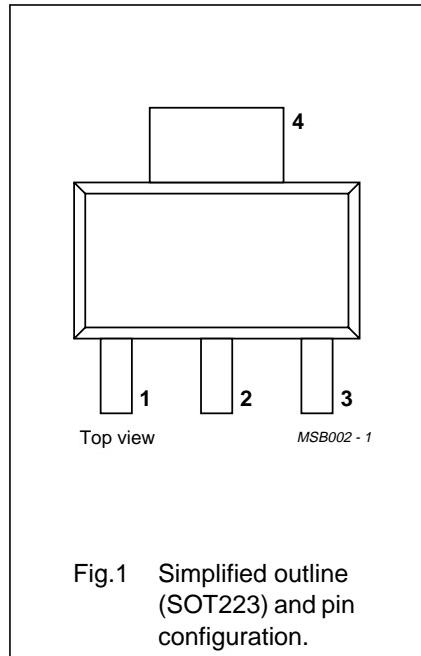


Fig.1 Simplified outline (SOT223) and pin configuration.

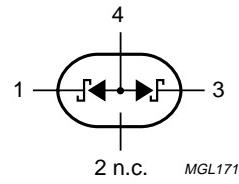


Fig.2 BAT160A diode configuration (symbol).

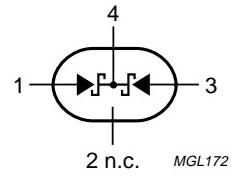


Fig.3 BAT160C diode configuration (symbol).

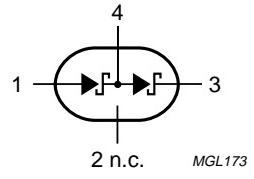


Fig.4 BAT160S diode configuration (symbol).

Schottky barrier double diodes

BAT160 series

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V_R	continuous reverse voltage		–	60	V
I_F	continuous forward current		–	1	A
I_{FSM}	non-repetitive peak forward current	$t_p = 8.3 \text{ ms}; \text{ half sinewave}; \text{ JEDEC method}$	–	10	A
I_{RSM}	non-repetitive peak reverse current	$t_p = 100 \mu\text{s}$	–	0.5	A
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C

ELECTRICAL CHARACTERISTICS

$T_{amb} = 25 \text{ }^{\circ}\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
Per diode				
V_F	forward voltage	see Fig.5 $I_F = 100 \text{ mA}$ $I_F = 1 \text{ A}$ $I_F = 2 \text{ A}$	400 650 850	mV
I_R	reverse current	$V_R = 60 \text{ V}; \text{ note 1}; \text{ see Fig.6}$ $V_R = 60 \text{ V}; T_j = 100 \text{ }^{\circ}\text{C}; \text{ note 1}; \text{ see Fig.6}$	350 8	μA mA
C_d	diode capacitance	$f = 1 \text{ MHz}; V_R = 4 \text{ V}; \text{ see Fig.7}$	60	pF

Note

1. Pulse test: $t_p = 300 \mu\text{s}; \delta = 0.02$.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th j-a}$	thermal resistance from junction to ambient	note 1	100	K/W

Note

1. Refer to SOT223 standard mounting conditions.

Schottky barrier double diodes

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GRAPHICAL DATA

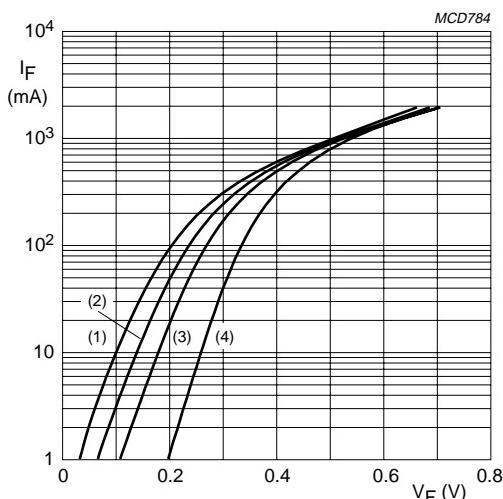


Fig.5 Forward current as a function of forward voltage; typical values.

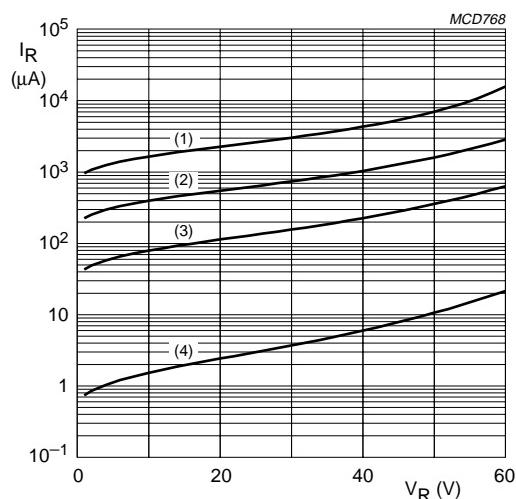
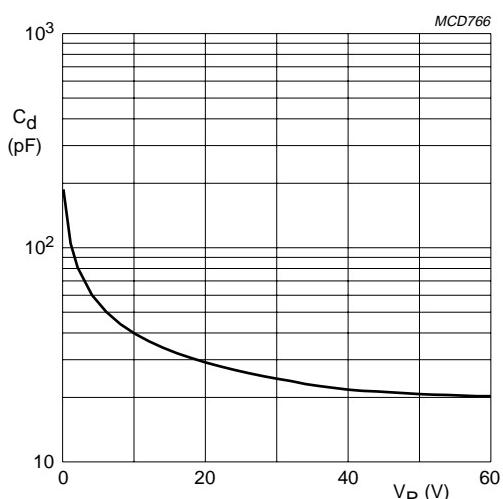


Fig.6 Reverse current as a function of reverse voltage; typical values.



$f = 1\text{ MHz}; T_{amb} = 25\text{ }^{\circ}\text{C}$.

Fig.7 Diode capacitance as a function of reverse voltage; typical values.

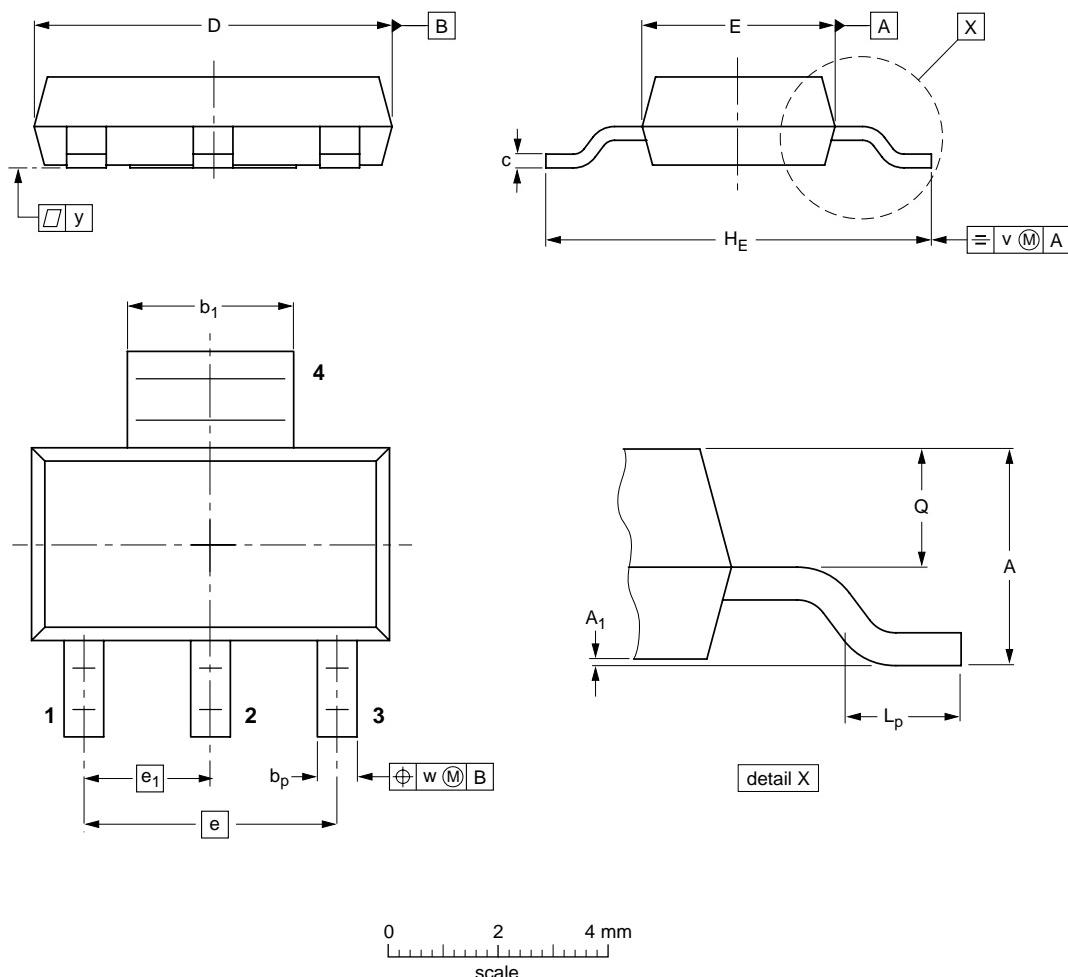
Schottky barrier double diodes

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PACKAGE OUTLINE

Plastic surface mounted package; collector pad for good heat transfer; 4 leads

SOT223



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁	b _p	b ₁	c	D	E	e	e ₁	H _E	L _p	Q	v	w	y
mm	1.8 1.5	0.10 0.01	0.80 0.60	3.1 2.9	0.32 0.22	6.7 6.3	3.7 3.3	4.6	2.3	7.3 6.7	1.1 0.7	0.95 0.85	0.2	0.1	0.1

OUTLINE VERSION	REFERENCES					EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ	SC-73			
SOT223				SC-73			-97-02-28 99-09-13

Schottky barrier double diodes

BAT160 series

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

Schottky barrier double diodes

BAT160 series

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Printed in The Netherlands

115002/03/08

Date of release: 1999 Sep 20

Document order number: 9397 750 06097

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